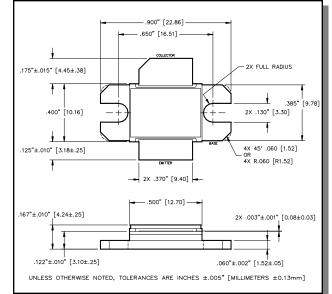
PH2226-110M

Radar Pulsed Power Transistor 110W, 2.2-2.6GHz, 100µs Pulse, 10% Duty

Features

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- · Diffused emitter ballasting resistors
- Gold metallization system
- · Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

Outline Drawing



Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V _{CES}	65	V
Emitter-Base Voltage	V _{EBO}	3.0	V
Collector Current (Peak)	Ι _C	15	А
Power Dissipation @ +25°C	P _{TOT}	583	W
Storage Temperature	T _{STG}	-65 to +200	°C
Junction Temperature	TJ	200	°C

Electrical Specifications: T_c = 25 ± 5°C (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	I _C = 40mA		BV _{CES}	65	-	V
Collector-Emitter Leakage Current	V _{CE} = 36V		I _{CES}	-	3.0	mA
Thermal Resistance	Vcc = 36V, Pin = 20W	F = 2.25, 2.55 GHz	R _{TH(JC)}	-	0.3	°C/W
Output Power	Vcc = 36V, Pin = 20W	F = 2.25, 2.55 GHz	P _{OUT}	110	-	W
Power Gain	Vcc = 36V, Pin = 20W	F = 2.25, 2.55 GHz	G _P	7.4	-	dB
Collector Efficiency	Vcc = 36V, Pin = 20W	F = 2.25, 2.55 GHz	η _c	40	-	%
Pulse Droop	Vcc = 36V, Pin = 20W	F = 2.25, 2.55 GHz	Droop	-	1.0	dB
Input Return Loss	Vcc = 36V, Pin = 20W	F = 2.25, 2.55 GHz	RL	-	-9	dB
Load Mismatch Tolerance	Vcc = 36V, Pin = 20W	F = 2.25, 2.55 GHz	VSWR-T	-	3:1	-
Load Mismatch Stability	Vcc = 36V, Pin = 20W	F = 2.25, 2.55 GHz	VSWR-S	-	1.5:1	-

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M/A-COM Products

Released, 22 Feb 08



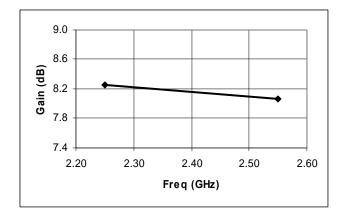
M/A-COM Products Released, 22 Feb 08

Radar Pulsed Power Transistor
110W, 2.2-2.6GHz, 100µs Pulse, 10% Duty

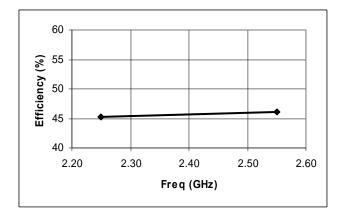
Typical RF Performance

Freq. (GHz)	Pin (W)	Pout (W)	Gain (dB)	lc (A)	Eff (%)	RL (dB)	Droop (dB)	VSWR-S (1.5:1)	VSWR-T (3:1)
2.25	20.0	134	8.26	0.83	45.3	-14.0	0.33	S	Р
2.55	20.0	128	8.07	0.77	46.1	-18.0	0.18	S	Р

Gain vs. Frequency

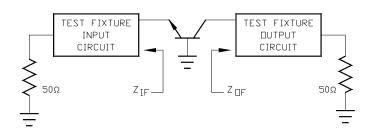


Collector Efficiency vs. Frequency



RF Test Fixture Impedance

F (GHz)	Z _{IF} (Ω)	Z _{OF} (Ω)		
2.25	2.8 - j3.4	4.1 - j2.9		
2.40	2.9 - j3.0	3.8 - j2.9		
2.55	3.1 - j2.6	3.3 - j2.7		



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